KODENSHI AUK

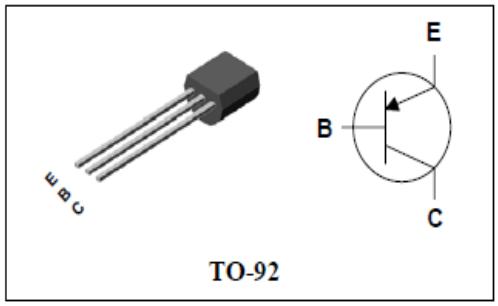
K2N5401

PNP Silicon Transistor

Descriptions

- General purpose amplifier
- High voltage application

PIN Connection



Features

- High collector breakdown voltage : V_{CBO} = -160V, V_{CEO} = -160V
- Low collector saturation voltage : $V_{CE(sat)}$=-0.5V(MAX.)
- Complementary pair with K2N5551

Ordering Information

Type NO.	Marking	Package Code
K2N5401	K2N5401□•	TO-92

□ : Year & Week Code •Dalian

Absolute Maximum Ratings (Ta=25°C)

Characteristic	Symbol	Ratings	Unit
Collector-Base voltage	V_{CBO}	-160	V
Collector-Emitter voltage	V_{CEO}	-160	V
Emitter-Base voltage	V_{EBO}	-5	V
Collector current	I_C	-600	mA
Collector dissipation	P_C	625	mW
Junction temperature	T_j	150	℃
Storage temperature	T_{stg}	-55~150	℃

Electrical Characteristics

(Ta=25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-Base breakdown voltage	BV_{CBO}	I_C=-100μA, I_E=0	-160	-	-	V
Collector-Emitter breakdown voltage	BV_{CEO}	I_C=-1mA, I_B=0	-160	-	-	V
Emitter-Base breakdown voltage	BV_{EBO}	I_E=-10μA, I_C=0	-5	-	-	V
Collector cut-off current	I_{CBO}	V_{CB}=-120V, I_E=0	-	-	-100	nA
Emitter cut-off current	I_{EBO}	V_{EB}=-3V, I_C=0	-	-	-100	nA
DC current gain	$h_{FE\ (1)}$	V_{CE}=-5V, I_C=-1mA	50	-		-
DC current gain	$h_{FE\ (2)}$	V_{CE}=-5V, I_C=-10mA	60	-	240	-
DC current gain	$h_{FE\ (3)}$	V_{CE}=-5V, I_C=-50mA	50	-		-
Collector-Emitter saturation voltage	$V_{CE(sat)(1)}^{*}$	I_C=-10mA, I_B=-1mA	-	-	-0.2	V
Collector-Emitter saturation voltage	$V_{CE(sat)(2)}^{*}$	I_C=-50mA, I_B=-5mA	-	-	-0.5	V
Base-Emitter saturation voltage	$V_{BE(sat)(1)}^{*}$	I_C=-10mA, I_B=-1mA	-	-	-1	V
Base-Emitter saturation voltage	$V_{BE(sat)(2)}^{*}$	I_C=-50mA, I_B=-5mA	-	-	-1	V
Transition frequency	f_T	V_{CE}=-10V, I_C=-10mA	100	-	400	MHz
Collector output capacitance	C_{ob}	V_{CB}=-10V, I_E=0, f=1MHz	-	-	6	pF

* : Pulse Tester : Pulse Width ≤300μs, Duty Cycle ≤2.0%

Electrical Characteristic Curves

Fig. 1 P_C-T_a

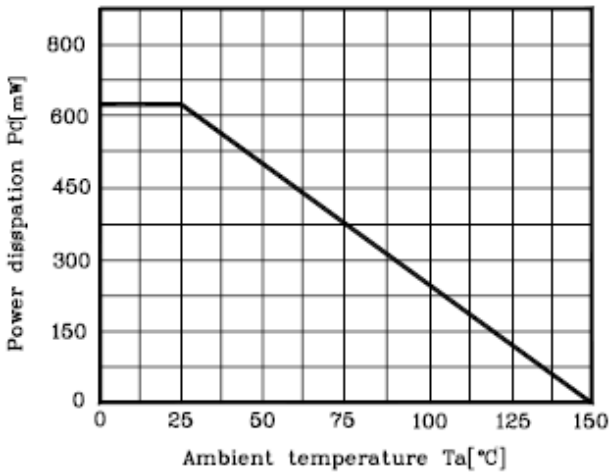


Fig. 2 I_C - V_{BE}

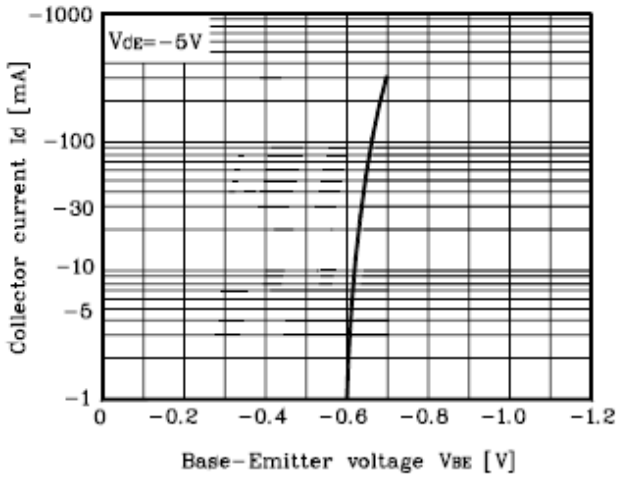


Fig. 3 f_T - I_C

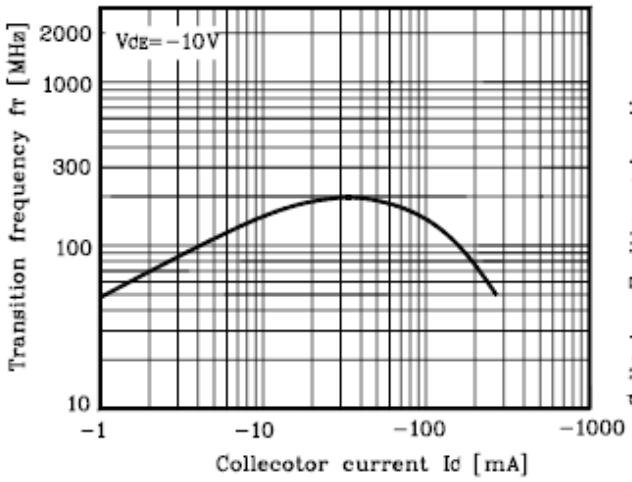


Fig. 4 $V_{CE(sat)}$, $V_{BE(sat)}$ - I_C

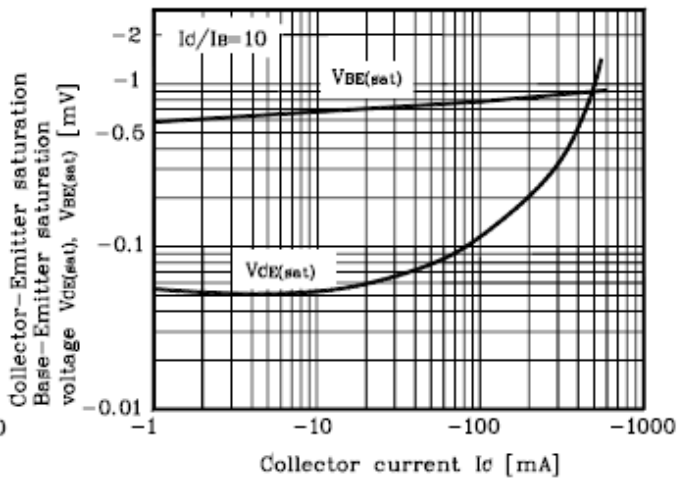
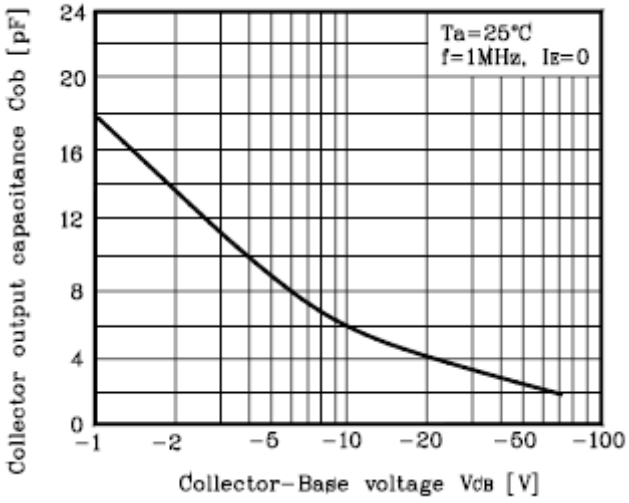
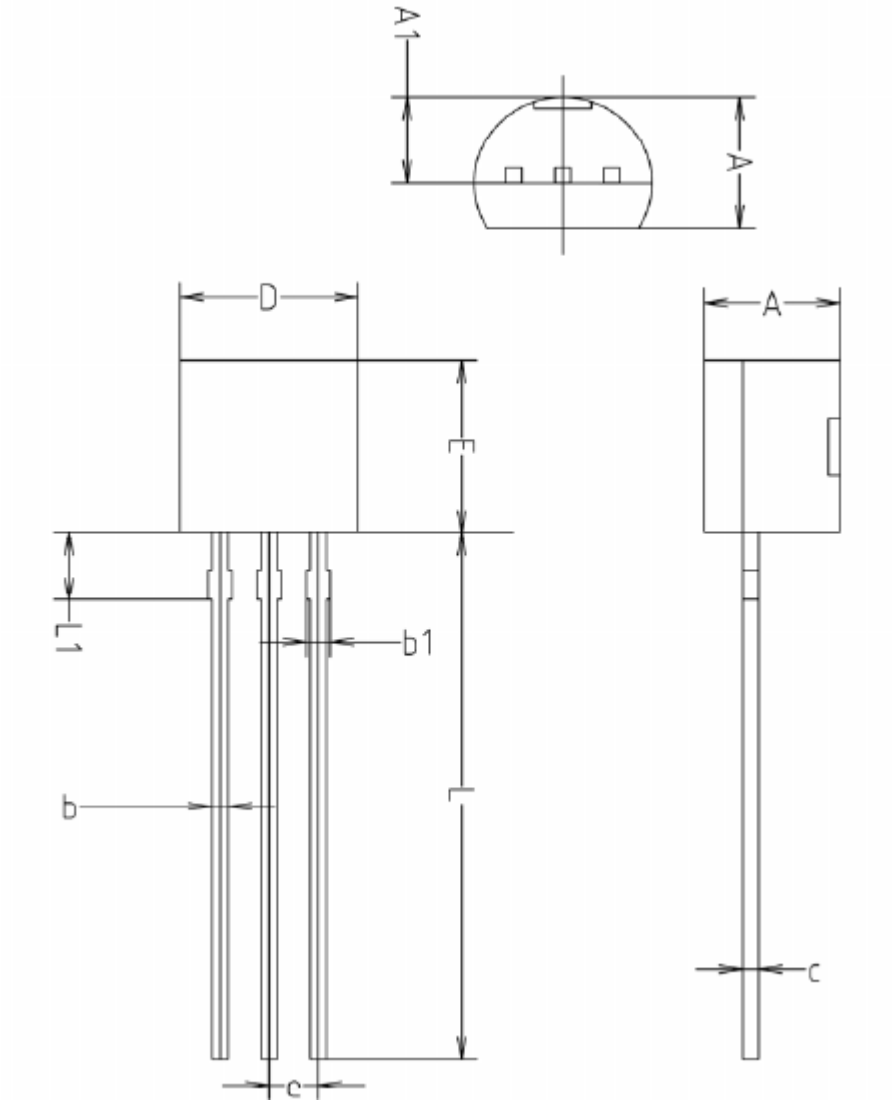


Fig. 5 C_{ob} - V_{CB}



Outline Dimension



SYMBOL	MILLMETERS(mm)		
	MINIMUM	NOMINAL	MAXIMUM
A	3.40	3.50	3.66
A1	2.46	2.51	2.59
b	0.39	0.44	0.53
b1	0.39	–	0.63
c	0.35	0.42	0.47
D	4.48	4.60	4.70
E	4.48	4.60	4.70
e	1.17	1.27	1.37
L	13.70	14.00	14.77
L1	1.55	1.70	2.15

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